InGaAs-APD/Preamp Receiver

FRM5N141GT

FEATURES

- Board mount type "GT" package: 17 pins
- InGaAs-APD with pre-amplifier
- Integrated Design Optimizes Performance at Bit Rates up to 10.7Gb/s
- Electrical Differential Output
- High Sensitivity: -26.5dBm
- Operates in both C and L wavelength bands



This APD with preamplifier is intended to function as an optical receiver at 1,310nm or 1,530-1,610nm in SONET, SDH, DWDM or other optical fiber systems operating up to 10.7Gb/s. The typical transimpedance (Zt) value of 1,200 Ω optimizes the total bandwidth for 10Gb/s application. The detector preamplifier is DC coupled and has an electrical differential output.



The FRM5N141GT incorporates a high bandwidth InGaAs APD photo diode, a GaAs amplifier in a hermetically sealed board mount type package. The APD is processed with modern epitaxial techniques resulting in a reliable performance over a wide range of operating conditions.

ABSOLUTE MAXIMUM RATINGS (T_C=25°C, unless otherwise specified)

Davamatav	Symbol	Rat	I I to th	
Parameter		Min.	Max.	Unit
Storage Temperature	T _{stg}	-40	+85	°C
Operating Temperature	Т _{ор}	-5	+75	°C
Supply Voltage	V _{SS}	-6	0	V
APD Reverse Voltage	VR	0	VB(Note)	V
APD Reverse Current	lR	-	4(peak)	mA

Note: Since VB may vary from device-to-device, VB data is attached to each device for reference.



OPTICAL & ELECTRICAL CHARACTERISTICS

(T_C=25°C, λ =1,550nm, V_{SS}=-5.2V, unless otherwise specified)

Parameter	Symbol			Limits			Unit
- unumeter	Cymbol			Min.		Max.	Onit
APD Responsivity		λ = 1,310nm, M=1		0.75 0.75	0.85 0.90	-	A/W
APD nesponsivity	R	$\lambda = 1,550$ nm, M=1 $\lambda = 1,610$ nm, M=1		-	0.80	-	
APD Breakdown Voltage	VB	ID = 10μA		20.0	25.0	30.0	V
Temperature Coefficient of VB	Γ	Note (1)		0.03	0.05	0.07	V/°C
AC Transimpedance	Zt	f = 750MHz, Single-end		800	1200	-	Ω
Maximum Output Voltage Swing	V _{clip}	Saturated Output Voltage		350	550	750	mV
Bandwidth	BW	-3dB from 750MHz,	M=9	6.0	7.5	8.5	GHz
		Pin=-20dBm	M=3	6.0	7.5	-	
Lower Cut-off Frequency	fcl	-3dB from 750MHz, Pin=-20dBm		-	40	100	kHz
Peaking	dpk	130MHz to BW, Pin=-20dBm, M=9		-	0.5		dB
Group Delay Deviation	GD	1GHz to 4GHz, Pin=-20dBm, M=9		-	30	-	ps _{p-p}
		1GHz to 6GHz, Pin=-20dBm, M=9		-	50	-	
Output Return Loss	S22	130MHz to 6GHz		-	12	-	dB
		130MHz to 8GHz		-	7	-	
Minimum Sensitivity	Pr	10Gb/s, NRZ, PRBS=2 ³¹ -1, B.E.R.=10 ⁻¹² ,	;	-	-26.5	-25.0	dBm
		VR=Optimum, Rext=13dB	;	-	-25.5	-24.0	
Maximum Overload	Po	10Gb/s, NRZ, PRBS=2 ³¹ -1, B.E.R.=10 ⁻¹² , M=3, Rext=13dB		-7	-5		dBm
Optical Return Loss	05:	$\lambda = 1,550r$	λ = 1,550nm		-	-	4D
	ORL	$\lambda = 1,310$ nm		27	-	-	dB
Power Supply Current	I _{SS}	-		-	110	130	mA
Power Supply Voltage	V _{SS}	-		-5.46	-5.20	-4.94	V
Thermistor Resistance	R _{th}	-		9.5	10.0	10.5	kΩ
Thermistor B Constant	В	-		3800	3900	4000	K
		L					

Note 1: $\Gamma = \Delta VB/dTc$

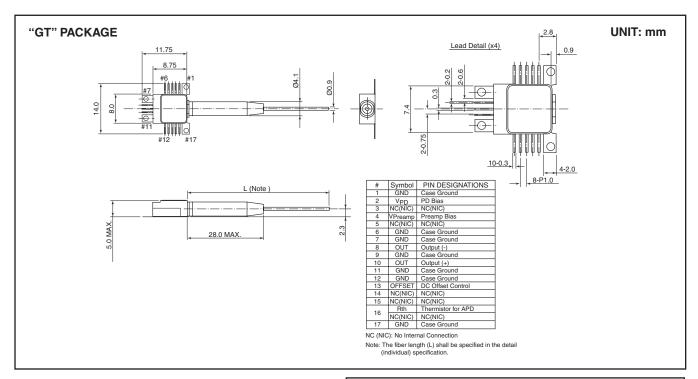
Note: All the parameters are measured with 50Ω load through external coupling capacitor.



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Notes	



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